

CentralTM Semiconductor Corp.

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Manufacturers of World Class Discrete Semiconductors

1N2154 THRU 1N2160
1N2154R THRU 1N2160R

SILICON RECTIFIER
25 AMPS, 50 TO 600 VOLTS

JEDEC DO-5 CASE

DESCRIPTION

The CENTRAL SEMICONDUCTOR 1N2154 Series Diffused Junction Silicon Rectifiers are designed for general purpose rectifier applications. Normal polarity is cathode to case. For reverse polarity and R suffix to Part No.

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (T_C=25°C unless otherwise noted)

		1N2154	1N2155	1N2156	1N2157	1N2158	1N2159	1N2160	
	SYMBOL	1N2154R	1N2155R	1N2156R	1N2157R	1N2158R	1N2159R	1N2160R	UNIT
Peak Reverse Voltage	PRV	50	100	200	300	400	500	600	V
DC Blocking Voltage	V _R	50	100	200	300	400	500	600	V
RMS Reverse Voltage	V _{R(RMS)}	35	70	140	210	280	350	420	V
Average Forward Current (T _C =145°C)	I _O	25	25	25	25	25	25	25	A
Peak Surge Current	*I _{FSM}	400	400	400	400	400	400	400	A
Max Forward Voltage Drop	*V _{FM}	0.6	0.6	0.6	0.6	0.6	0.6	0.6	V
Max Forward Voltage Drop (I _T =40A)	V _{FM}	1.1	1.1	1.1	1.1	1.1	1.1	1.1	V
Max Leakage Current*	I _R	5.0	4.5	4.0	3.5	3.0	2.5	2.0	mA
Max Thermal Resistance	θ _{JC}	1.5	1.5	1.5	1.5	1.5	1.5	1.5	°C/W
Operating and Storage Junction Temperature	T _J , T _{stg}	-65 TO +200							°C

*Full Cycle (60Hz) Average, T_C=145°C